ΡΛΝ	JIT
	SEMI
	CONDUCTOR

60V N-Channel Enhancement Mode MOSFET

Voltage

Current 40 A

Features

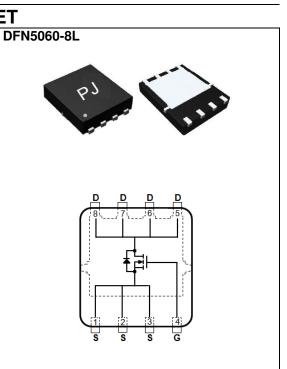
• $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@15A < 21m\Omega$

60 V

- $R_{DS(ON)}$, V_{GS} @4.5V, I_D @8A<24m Ω
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0028 ounces, 0.08 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	60	Ň	
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T _C =25°C		40		
	$T_{\rm C}=100^{\circ}{\rm C}$	ID	25	А	
Pulsed Drain Current (Note 1)	T _c =25°C	I _{DM}	160		
Power Dissipation	T _c =25°C	D-	100	14/	
	T _C =100°C	PD	50	W	
Continuous Drain Current (Note 4)	T _A =25°C		6.5		
	T _A =70°C	ID	5	A	
Power Dissipation	T _A =25°C		2.4		
	T _A =70°C	PD	1.6	W	
Single Pulse Avalanche Energy (Note 6)		E _{AS}	42	mJ	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	R _{θJC}	1.5	00.00	
	Junction to Ambient	R _{eJA}	62.5	°C/W	



Electrical Characteristics (T_A=25[°]C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} =0V, I _D =250uA	60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1	1.73	2.5	V
Drain-Source On-State Resistance		V_{GS} =10V, I_{D} =15A	-	18	21	mΩ
	$R_{DS(on)}$	V _{GS} =4.5V, I _D =8A	-	21	24	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg	V_{DS} =30V, I _D =15A, V_{GS} =10V ^(Note 2,3)	-	28	-	nC
Gate-Source Charge	Q _{gs}		-	3.5	-	
Gate-Drain Charge	Q _{gd}		-	6.5	-	
Input Capacitance	Ciss	V _{DS} =20V, V _{GS} =0V, f=1MHZ	-	1680	-	pF
Output Capacitance	Coss		-	115	-	
Reverse Transfer Capacitance	Crss		-	85	-	
Turn-On Delay Time	td _(on)	V_{DD} =30V, I_{D} =1A, V_{GS} =10V, R_{G} =6 Ω (Note 2.3)	-	7.2	-	
Turn-On Rise Time	t _r		-	38	-	
Turn-Off Delay Time	td _(off)		-	34	-	ns
Turn-Off Fall Time	t _f	(-	8.2	-	
Drain-Source Diode	-		•	•	•	•
Maximum Continuous Drain-Source	I				10	
Diode Forward Current	I _S		-	-	40	A
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.7	1	V

NOTES :

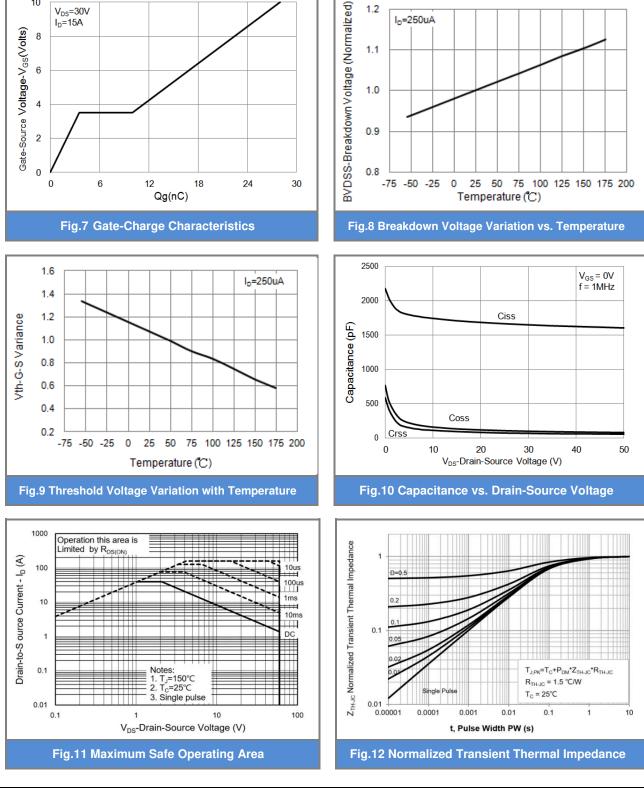
- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150$ °C. Ratings are based on low frequency and duty cycles to keep initial $T_J = 25$ °C.
- 4. The maximum current rating is package limited.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, $I_{\text{AS}}{=}29\text{A},\,V_{\text{DD}}{=}25\text{V},\,V_{\text{GS}}{=}10\text{V}.$
- 7. Guaranteed by design, not subject to production testing.

SEMI

PANJ

CONDUCTOR PJQ5466A-AU **TYPICAL CHARACTERISTIC CURVES** 20 20 V_{DS}=5V 10V,8V,5V,4V V_{GS}=3.5V IDS-Drain-to-S ource Current(A) I_{DS}-Drain-to-Source Current(A) 15 15 10 10 V_{GS}=3V 5 T_=25℃ 5 T_J=125℃ 0 0 0 1.6 2.2 3.4 2 3 5 1 2.8 4 V_{DS}-Drain-to-Source Voltage(V) V_{GS}-Gate-to-Source Voltage(V) **Fig.1 Output Characteristics Fig.2 Transfer Characteristics** 27 2.5 R_{bs}(on)- On-Resistance (Normalized) $R_{DS}(on)$ - On-Resistance(m Ω) 2.0 24 V_{GS}= 4.5V V_{G8}=10V, I_D=15A 1.5 21 1.0 V_{GS}= 10V V_{G8}=4.5V, I_D=8A 18 0.5 0.0 15 -75 -50 -25 0 25 50 75 100 125 150 175 200 0 20 5 10 15 I_{DS}-Drain-to-Source Current(A) Temperature (°C) Fig.3 On-Resistance vs. Drain Current Fig.4 On-Resistance vs. Junction temperature 60 10 I_D=7.5A I_S-Source to-Drain Current(A) $R_{DS}(on)$ - On-Resistance(m Ω) **50** 1 40 T_j=125℃ 30 T_i=125℃ Tj=25℃ 0.1 T_i=25℃ 20 10 0.01 0 2.5 5 7.5 10 0 0.3 0.6 0.9 1.2 V_{GS}-Gate-to-Source Voltage(V) V_{SD}-Source-to-Drain Voltage(V)

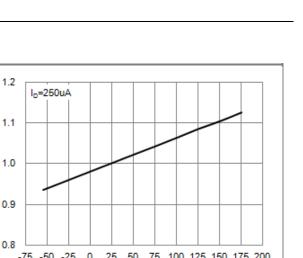
Fig.6 Source-Drain Diode Forward Voltage



TYPICAL CHARACTERISTIC CURVES

March 28,2019-REV.00





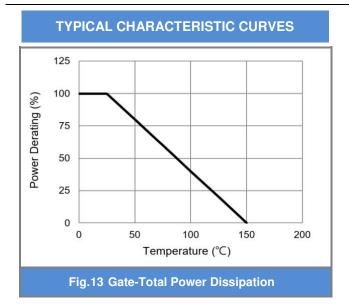
V_{DS}=30V

I_D=15A

10

PJQ5466A-AU



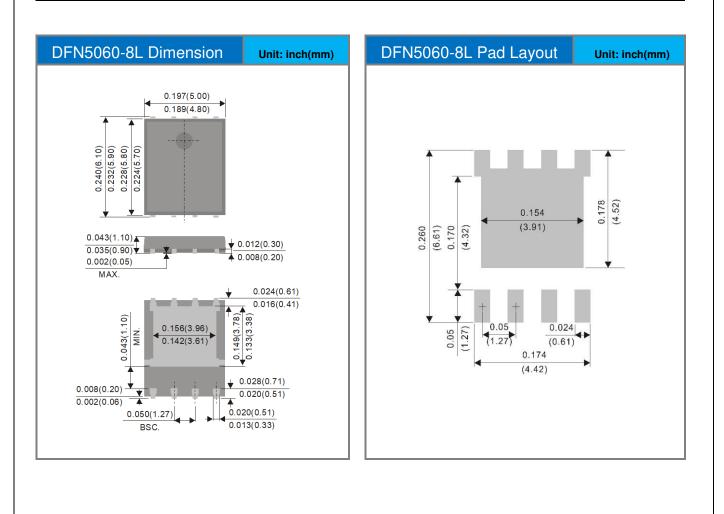




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5466A-AU_R2_000A1	DFN5060-8L	3000pcs / 13" reel	Q5466A	Halogen free

Packaging Information & Mounting Pad Layout





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